# NSN 5962-01-341-5892

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-341-5892

Overall Length:
Overall Length: 1.280 inches
Overall Height: 0.400 inches
Body Length:
1.280 inches
Body Width: Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.02 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Synchronous and monolithic and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
185.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
10.00 input pascal dense structural 65 and 13.00 output pascal dense structural 65 $$
Time Rating Per Chacteristic:
40.00 nanoseconds access
Memory Device Type:
Prom
Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# NSN 5962-01-341-5892

Memory Microcircuit - Page 2 of 2

## AeroBase Group

### Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

---

#### Demilitarization:

Yes - demil/mli

Fiig:

A458a0